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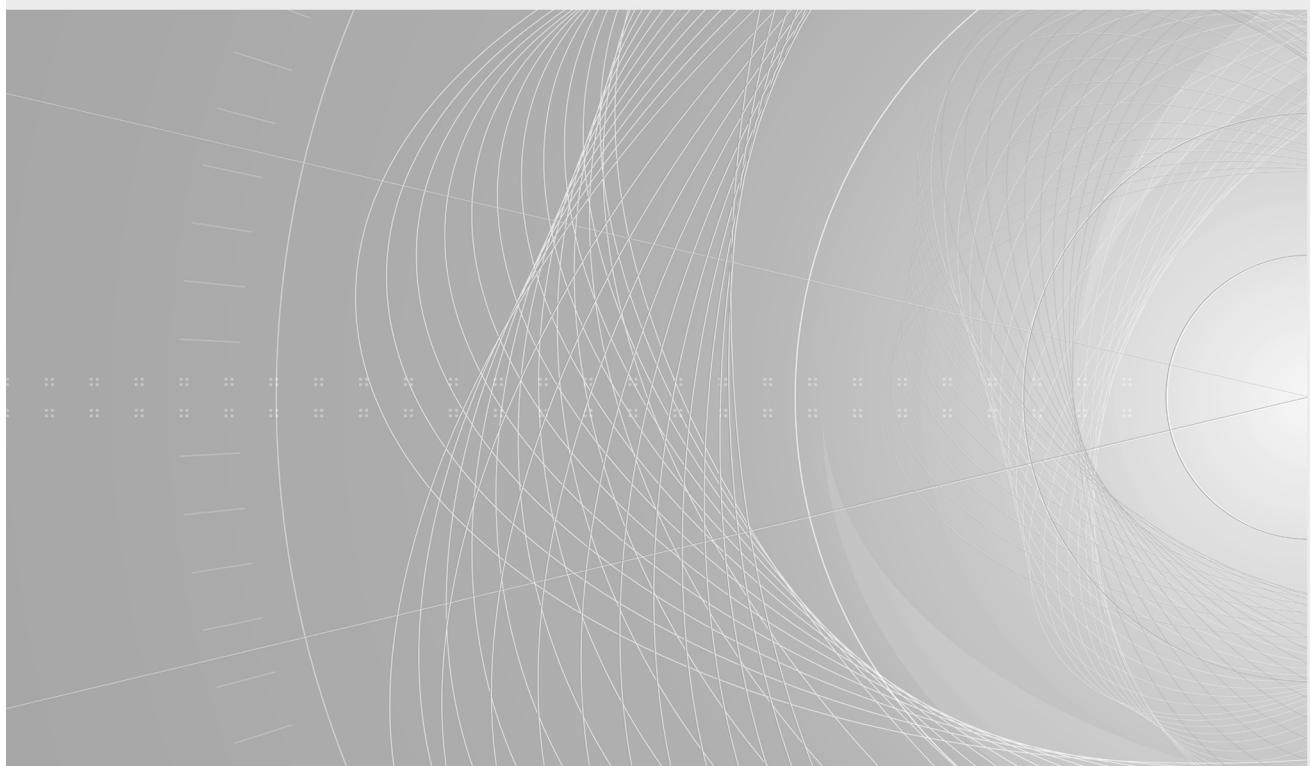
EMC IC modelling iTeh STANDARD PREVIEW

Part 2: Models of integrated circuits for EMI behavioural simulation – Conducted emissions modelling (ICEM-CE)

Modèles de circuits intégrés pour la CEM –

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Partie 2: Modèles de circuits intégrés pour la simulation du comportement lors de perturbations électromagnétiques – Modélisation des émissions conduites (ICEM-CE)





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EMC IC modellingⁱTeh STANDARD PREVIEW

Part 2: Models of integrated circuits for EMI behavioural simulation – Conducted emissions modelling (ICEM-CE)

[IEC 62433-2:2017](#)

Modèles de circuits intégrés pour la CEM – Partie 2: Modèles de circuits intégrés pour la simulation du comportement lors de perturbations électromagnétiques – Modélisation des émissions conduites (ICEM-CE)

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EMC IC MODELLING –

Part 2: Models of integrated circuits for EMI behavioural simulation – Conducted emissions modelling (ICEM-CE)

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International Standard IEC 62433-2 has been prepared by subcommittee 47A: Integrated Circuits, of IEC technical committee 47: Semiconductor devices.

This second edition cancels and replaces the first edition published in 2008. This edition constitutes a technical revision.

This edition includes the following significant technical changes with respect to the previous edition:

Incorporation of an XML based exchange format for model representation.

The text of this standard is based on the following documents:

FDIS	Report on voting
47A/999/FDIS	47A/1007/RVD

Full information on the voting for the approval of this standard can be found in the report on voting indicated in the above table.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

A list of all parts in the IEC 62433 series, published under the general title *EMC IC modelling*, can be found on the IEC website.

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EMC IC MODELLING –

Part 2: Models of integrated circuits for EMI behavioural simulation – Conducted emissions modelling (ICEM-CE)

1 Scope

This part of IEC 62433 specifies macro-models for an Integrated Circuit (IC) to simulate conducted electromagnetic emissions on a printed circuit board. The model is commonly called Integrated Circuit Emission Model – Conducted Emission (ICEM-CE).

The ICEM-CE macro-model can also be used for modelling an IC-die, a functional block and an Intellectual Property (IP) block.

The ICEM-CE macro-model can be used to model both digital and analogue ICs.

Basically, conducted emissions have two origins:

- conducted emissions through power supply terminals and ground reference structures;
- conducted emissions through input/output (I/O) terminals.

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This standard defines structures and components of the macro-model for EMI simulation taking into account the IC's internal activities.

IEC 62433-2:2017
<https://standards.iteh.ai/catalog/standards/sist/832430e2-7d22-43cf-8145-377667c2a8fa/iec-62433-2-2017>

This part of IEC 62433 has two main parts:

- the first is the electrical description of ICEM-CE macro-model elements along with the specific requirements for information.
- the second part proposes a universal data exchange format called CEML based on XML. This format allows encoding the ICEM-CE in a more useable and generic form for simulating the conducted emissions.

2 Normative references

The following documents are referred to in the text in such a way that some or all of their content constitutes requirements of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC TS 62433-1:2011, *EMC IC modelling – Part 1: General modelling framework*

CISPR 17, *Methods of measurement of the suppression characteristics of passive EMC filtering devices*

3 Terms, definitions, abbreviations and conventions

3.1 Terms and definitions

For the purposes of this document, the following terms and definitions apply.

3.1.1**external terminal**

terminal of an integrated circuit (IC) macro-model which interfaces the model to the external environment of the IC

EXAMPLE Power supply pins and input/output pins.

Note 1 to entry: In this part of IEC 62433, the name of each external terminal starts with "ET".

3.1.2**internal terminal**

terminal of an integrated circuit (IC) macro-model's component which interfaces the component to other components of the IC macro-model

Note 1 to entry: In this part of IEC 62433, the name of each internal terminal starts with "IT".

3.1.3**section**

XML element placed one level below the root element or within another section and that contains one or more XML elements, but no value

3.1.4**parent**

keyword which is one level above another keyword

3.1.5**iTeh STANDARD PREVIEW****child**

keyword which is one level below another keyword (standards.iteh.ai)

3.1.6**[IEC 62433-2:2017](#)****parser**

<https://standards.iteh.ai/catalog/standards/sist/832430e2-7d22-43cf-8145-377607c2a81a> IEC 62433-2:2017

tool for syntactic analysis of data that is encoded in a specified format

3.1.7**S-parameter**

scattering parameter

S_{ij}

element of the S-matrix expressing the transmission and reflection coefficients of a device

Note 1 to entry: The most commonly used, each S-parameter relates the complex electric field strength of a reflected or transmitted wave to that of an incident wave; the subscripts of a typical S-parameter S_{ij} refer to the output and input ports related by the S-parameter, which may vary with frequency.

[SOURCE: CISPR 17:2011, 3.1.13]

3.1.8**CEML**

Conducted Emissions Markup Language

data exchange format for ICEM-CE macro-model

Note 1 to entry: This note applies to the French language only.

3.1.9**CEMLBase**

Conducted Emissions Markup Language Base

abstract type from which all CEML model components are directly or indirectly derived in the ICEM-CE macro-model definition

3.1.10**PDN**

Passive Distribution Network

component of an IC model that represents the characteristics of propagation path of electromagnetic noises such as power distribution network

[SOURCE: IEC TS 62433-1:2011, 3.4]

3.1.11**IA**

Internal Activity

component of an IC model represented by a current or voltage source, which originates in activity of active devices in an IC or in a portion of the IC

[SOURCE: IEC TS 62433-1:2011, 3.3]

3.1.12**IBC**

Inter-Block Coupling

network of passive elements that presents a coupling effect between circuit blocks within an IC

[SOURCE: IEC TS 62433-1:2011, 3.5]

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3.1.13**VNA**

Vector Network Analyzer

network analyzer capable of measuring complex values of the S-parameters

[IEC 62433-2:2017](#)

[SOURCE: CISPR 16-1-4:2010, 3.1.21, modified — for VNA with two or more ports]
<https://standards.iteh.ai/catalog/standards/sist/833430e2-7d22-43cf-8145-377667c2a8fa/iec-62433-2-2017>

3.2 Abbreviations

CEM Conducted Emission Model

XML eXtensible Markup Language

SPICE Simulation Program with Integrated Circuit Emphasis

3.3 Conventions

For the sake of clarity, but with some exceptions, the writing conventions of XML have been used in text and tables.

The symbol “ μ ” is used in the text part to define micro = 1e-6. The symbol “u” is used in the XML parts to define the micro = 1e-6.

4 Philosophy

4.1 General

Integrated circuits will have more and more gates on silicon and technical progress will develop faster. To predict the electromagnetic behaviour of equipment, it is required to model the switching of the input and output interface and the internal activities of an IC effectively.

Figure 1 depicts an example of decomposition of an IC to enable conducted emissions analysis. The internal digital activity (culprit) is a source of electromagnetic noise that originates in switching of active devices. The coupling path propagates the emissions to the

IC's external terminals: pins/pads. The coupling path is the power distribution network or I/O lines inside the IC.

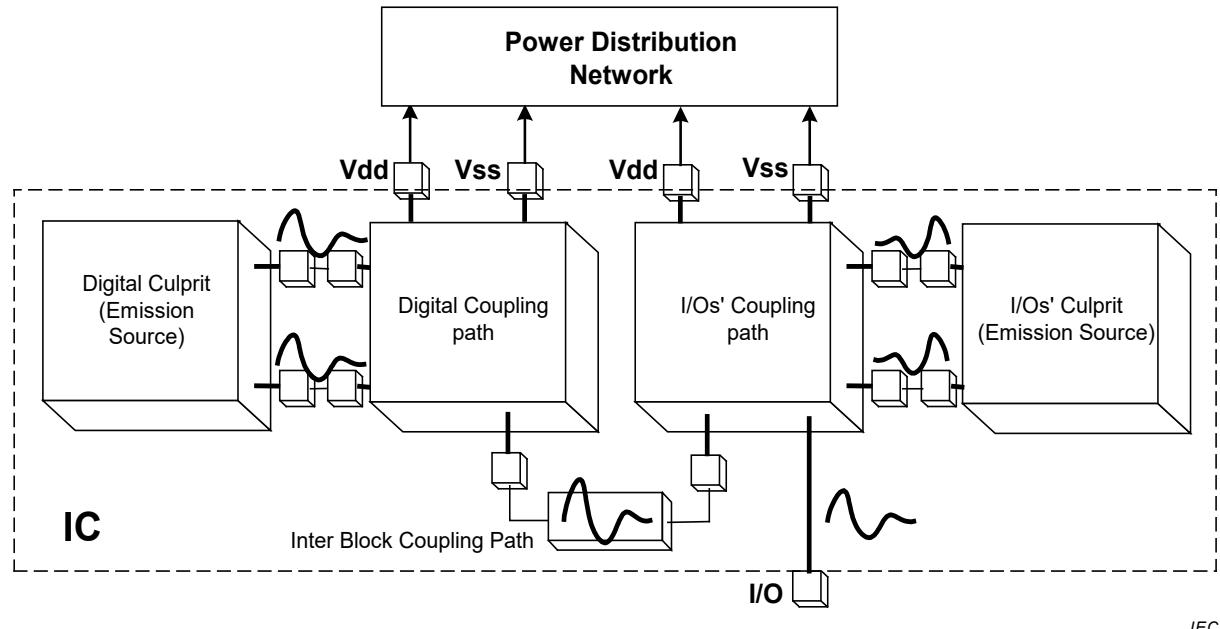


Figure 1 – Decomposition example of a digital IC for conducted emissions analysis

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4.2 Conducted emission from core activity (digital culprit) ([standards.iteh.ai](https://standards.iteh.ai/catalog/standards/sist/832430e2-7d22-45cf-8145-377667c2a8fa/iec-62433-2-2017))

The current transients are created in the core area on the IC-die. Due to the characteristics of the digital coupling paths, the passive distribution network on printed circuit board (PCB) and the availability of on-chip decoupling, a portion of these current transients will occur at the power supply pins of the IC. <https://standards.iteh.ai/catalog/standards/sist/832430e2-7d22-45cf-8145-377667c2a8fa/iec-62433-2-2017>

NOTE These off-chip power supply currents can be measured according to the IEC 61967 series [1]¹.

4.3 Conducted emission from I/O activity

I/Os activities may create voltage fluctuations of power and ground levels, and conducted emissions appear at power and ground pins through the I/Os' coupling path. And the output signals at output pins themselves are sources of conducted emissions to the printed circuit boards.

NOTE The measurement set-up is done according to the IEC 61967 series [1].

4.4 Data exchange format

ICEM-CE macro-model data is arranged in a decipherable nested manner using XML format. The objective of this exchange format, called Conducted Emissions Markup Language (CEML), is to create simple and practical universal access to ICEM-CE macro-model. The preliminary definitions for XML representation is given in Annex A. The CEML keywords and their usage rules are detailed in Annex B. An example ICEM-CE macro-model, in CEML format, is given in Annex C.

¹ Numbers in square brackets refer to the Bibliography.

5 ICEM-CE basic components

5.1 General

The basic components are component parts of the IC macro-model or block component or sub-model component. The basic components of the ICEM-CE macro-model are defined in 5.2 and 5.3.

NOTE The block component and the sub-model component are defined in 6.3.1 and 6.4.1 respectively.

5.2 Internal Activity (IA)

5.2.1 General

The Internal Activity (IA) component is the electromagnetic noise source that originates in switching of active devices in the IC or in a portion of the IC. This component is applicable for both analogue and digital circuitry.

The IA is described using an independent current source or an independent voltage source with two internal terminals. Figure 2 illustrates an example of an independent current source.

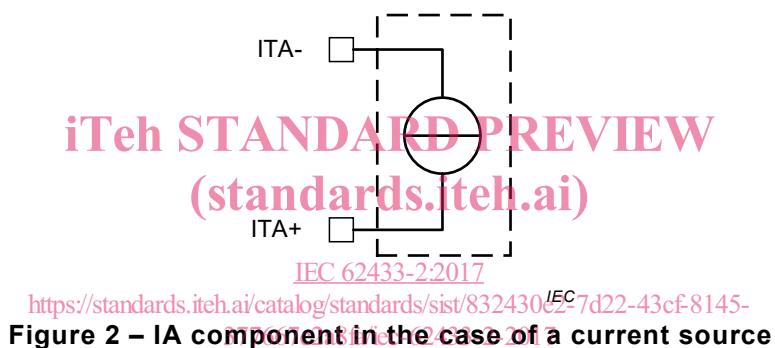


Figure 2 – IA component in the case of a current source

The characteristics of IA component are typically described in the time domain, and the characteristics can also be described in the frequency domain.

The description of an IA component shall contain the following information.

- Name of the IA component
- Names of its internal terminals
- Operational mode or test vector
- Domain (time or frequency)
- Definition of origin of time, and cycle-time for the operational mode (for time domain)
- Definition of origin of phase (for frequency domain)
- Operational conditions and applicable ranges
 - a) Power supply voltage ranges
 - b) Temperature range
 - c) Frequency range
- Characteristics of the IA
 - a) Current or voltage waveform over the whole cycle-time (for time domain)
 - b) Current or voltage amplitude and phase, versus frequency over the whole frequency range (for frequency domain)